

# **FDA28N50** N-Channel UniFET<sup>TM</sup> MOSFET 500 V, 28 A, 155 mΩ

### Features

- $R_{DS(on)}$  = 122 m $\Omega$  (Typ.) @  $V_{GS}$  = 10 V,  $I_D$  = 14 A
- Low Gate Charge (Typ. 80 nC)
- Low C<sub>rss</sub> (Typ. 42 pF)
- 100% Avalanche Tested
- RoHS Compliant

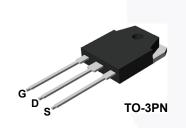
## Applications

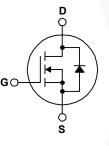
- PDP TV
- Uninterruptible Power Supply
- AC-DC Power Supply

## May 2014

## Description

UniFET<sup>TM</sup> MOSFET is Fairchild Semiconductor's high voltage MOSFET family based on planar stripe and DMOS technology. This MOSFET is tailored to reduce on-state resistance, and to provide better switching performance and higher avalanche energy strength. This device family is suitable for switching power converter applications such as power factor correction (PFC), flat panel display (FPD) TV power, ATX and electronic lamp ballasts.





## MOSFET Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted.

Symbol		Parameter		FDA28N50	Unit
V <sub>DSS</sub>	Drain to Source Voltage		500	V	
V <sub>GSS</sub>	Gate to Source Voltage			±30	V
ID	Drain Current	- Continuous (T <sub>C</sub> = 25 <sup>o</sup> C)		28	Α
		- Continuous ( $T_C = 100^{\circ}C$ )		17	
I <sub>DM</sub>	Drain Current	- Pulsed	(Note 1)	112	А
E <sub>AS</sub>	Single Pulsed Avalanche Energy		(Note 2)	2391	mJ
I <sub>AR</sub>	Avalanche Current		(Note 1)	28	А
E <sub>AR</sub>	Repetitive Avalanche Energy		(Note 1)	31	mJ
dv/dt	Peak Diode Recovery dv/dt		(Note 3)	5	V/ns
P <sub>D</sub>	Power Dissipation	$(T_{\rm C} = 25^{\rm o}{\rm C})$		310	W
		- Derate Above 25°C		2.5	W/ºC
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range			-55 to +150	°C
TL	Maximum Lead Temperatu	re for Soldering, 1/8" from Case for 5	Seconds	300	°C

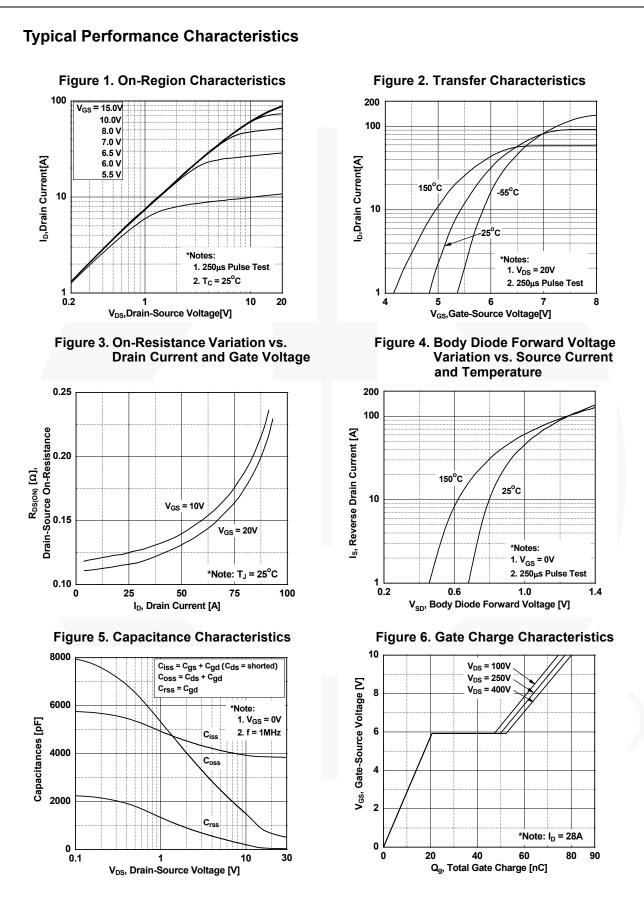
## Thermal Characteristics

Symbol	Parameter	FDA28N50	Unit
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case, Max.	0.4	°C/W
$R_{\thetaJA}$	Thermal Resistance, Junction to Ambient, Max.	40	

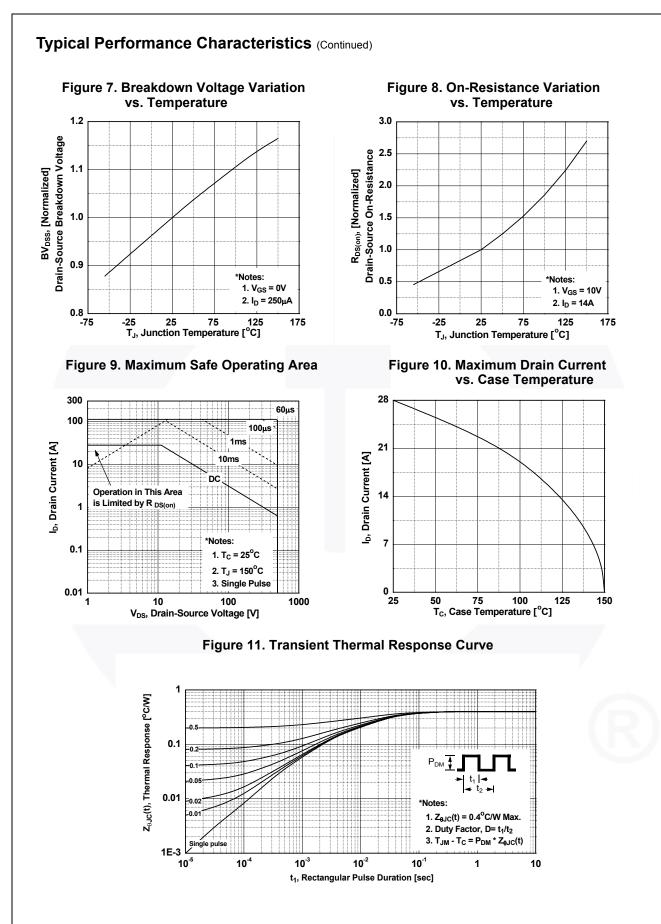
FDA28N50
— N-Channel
MOSFET

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N/A       Min.     Typ       500     -       -     0.5       -     0.5       -     -       3.0     -       -     0.12       -     34	<ul> <li>Max.</li> <li>-</li> <li>9</li> <li>-</li> <li>10</li> <li>±100</li> <li>±100</li> <li>25.0</li> <li>0.155</li> </ul>	units Uni V V/°C μA nA
500     -       -     0.5       -     -       -     -       -     -       3.0     -       -     0.12	- 9 - 1 10 ±100 22 0.155	V V/°C μΑ nA
500     -       -     0.5       -     -       -     -       -     -       3.0     -       -     0.12	- 9 - 1 10 ±100 22 0.155	V V/°C μΑ nA
- 0.5    3.0 - 0.12	1 10 ±100 5.0 22 0.155	V/ºC μA nA
- 0.5    3.0 - 0.12	1 10 ±100 5.0 22 0.155	V/ºC μA nA
  3.0 - - 0.12	1 10 ±100 5.0 22 0.155	μA nA
  3.0 - - 0.12	1 10 ±100 5.0 22 0.155	μA nA
  3.0 - - 0.12	10 ±100 5.0 22 0.155	nA
 3.0 - - 0.12	±100 5.0 22 0.155	nA
3.0 - - 0.12	5.0 22 0.155	1
- 0.12	0.155	V
- 0.12	0.155	V
- 34		Ω
	- 1	S
206	C 5140	~
- 386		pF pF
- 42		pF
- 42		nC
- 21		nC
- 32		nC
	•	
- 56	122	ns
- 126	6 262	ns
- 210	0 430	ns
- 110	230	ns
	28	A
		A
		V
		ns
		μC
	- 120 - 210 - 110  	- 126 262 - 210 430 - 110 230 28 112 1.4 - 530 -

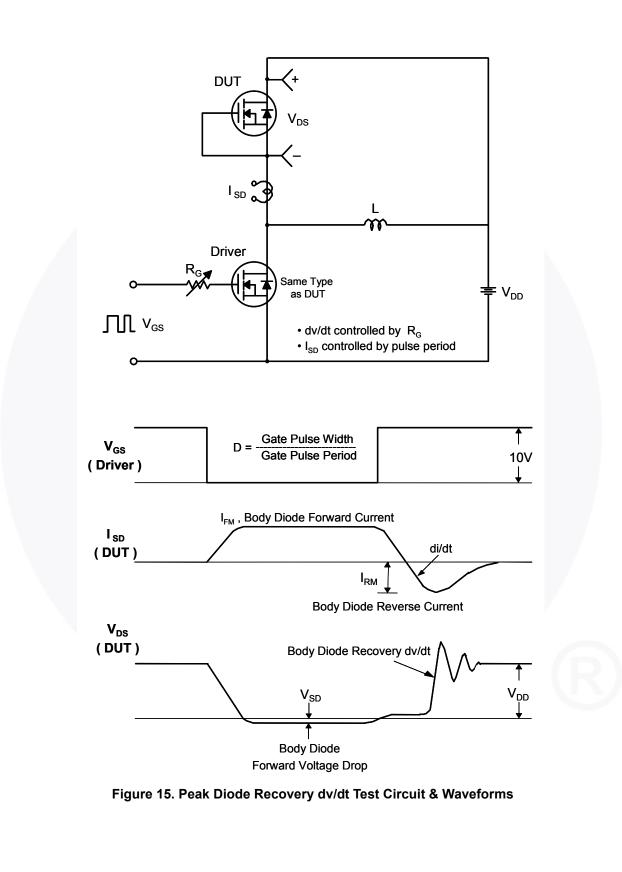


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 $V_{GS}$ ξ ק  $\mathsf{Q}_\mathsf{g}$ V<sub>DS</sub>  $\mathsf{Q}_{\mathsf{gd}}$  $\mathsf{Q}_{\mathsf{gs}}$ • DUT I<sub>G</sub> = const. Charge Figure 12. Gate Charge Test Circuit & Waveform R VDS V<sub>DS</sub> 90% ο V<sub>DD</sub> GS  $\mathsf{R}_{\mathsf{G}}$ 10% V<sub>GS</sub> DUT V<sub>GS</sub> ∏ o Figure 13. Resistive Switching Test Circuit & Waveforms L  $E_{AS} = \frac{1}{2} L I_{AS}^2$  $V_{DS}$  $\mathsf{BV}_{\mathsf{DSS}}$ ID o AS  $R_{G}$ **∔** ∨<sub>DD</sub>  $I_{D}(t)$ V<sub>GS</sub>  $V_{DS}(t)$  $V_{\text{DD}}$ DUT Time t<sub>p</sub> Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms

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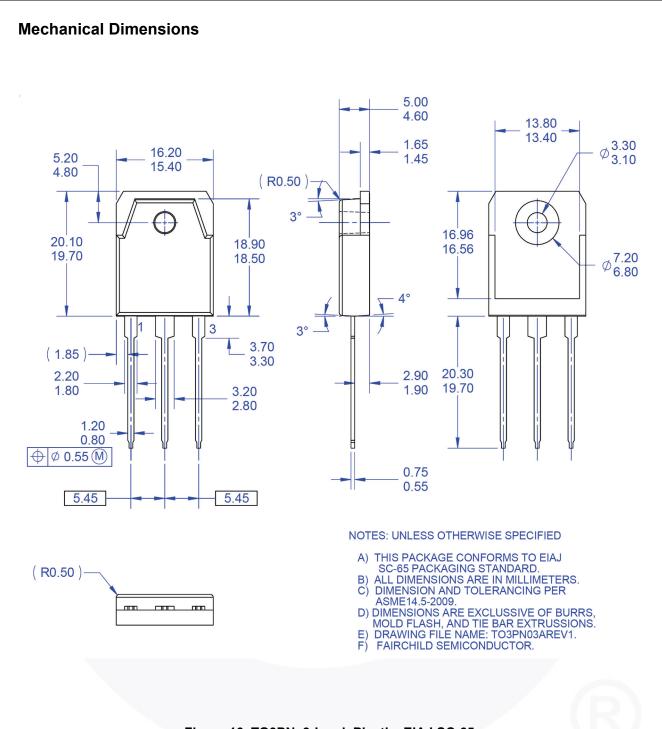


Figure 16. TO3PN, 3-Lead, Plastic, EIAJ SC-65

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